

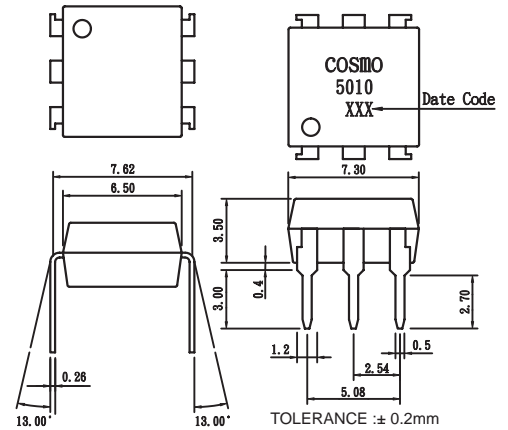
Features

1. High current transfer ratio (V_{CEO}:300V MIN)
(CTR:MIN.600% at I_F=1mA, V_{ce}=2V)
2. High isolation voltage between input and output
(Viso:5000Vrms).
3. Compact dual-in-line package.
4. Available package : DIP/ SMD/ H. (For Package Dimension please refer to page 82)

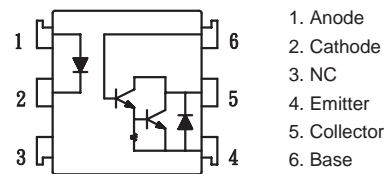
Applications

1. System appliances, measuring instruments.
2. Industrial robots.
3. Copiers, automatic vending machines.
4. Signal transmission between circuits of different potentials and impedances.
5. Telephone sets.
6. Copiers, facsimiles.
7. Interface with various power supply circuits, power distribution boards.
8. Numerical control machines.

Outside Dimension : Unit (mm)



Schematic : Top View



Absolute Maximum Ratings

(Ta=25°C)

| Parameter | | Symbol | Rating | Unit |
|---------------------------------|-----------------------------|------------------|-------------|------------------|
| Input | Forward current | I _F | 50 | mA |
| | Peak forward current | I _{FM} | 1 | A |
| | Reverse voltage | V _R | 6 | V |
| | Power dissipation | P _D | 70 | mW |
| Output | Collector-emitter voltage | V _{CEO} | 300 | V |
| | Collector-base voltage | V _{CB0} | 300 | V |
| | Emitter-base voltage | V _{EBO} | 6 | V |
| | Collector current | I _C | 150 | mA |
| | Collector power dissipation | P _C | 200 | mW |
| Total power dissipation | | P _{tot} | 200 | mW |
| Isolation voltage 1 minute | | Viso | 5000 | V _{rms} |
| Operating temperature | | T _{opr} | -30 to +100 | °C |
| Storage temperature | | T _{stg} | -55 to +125 | °C |
| Soldering temperature 10 second | | T _{sol} | 260 | °C |

Electro-optical Characteristics

(Ta=25°C)

| Parameter | | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--------------------------|--------------------------------------|-----------------------|---|--------------------|------|------|------|
| Input | Forward voltage | V _F | I _F =20mA | — | 1.2 | 1.4 | V |
| | Peak forward voltage | V _{FM} | I _{FM} =0.5A | — | — | 3.5 | V |
| | Reverse current | I _R | V _R =4V | — | — | 10 | uA |
| | Terminal capacitance | C _t | V=0, f=1kHz | — | 30 | — | pF |
| Output | Collector dark current | I _{CEO} | V _{CE} =200V, I _F =0 | — | — | 1 | uA |
| Transfer characteristics | Current transfer ratio | CTR | I _F =1mA, V _{CE} =2V | 600 | — | 9000 | % |
| | Collector-emitter saturation voltage | V _{CE (sat)} | I _F =20mA, I _C =5mA | — | — | 1.5 | V |
| | Isolation resistance | Riso | DC500V | 5X10 ¹⁰ | — | — | ohm |
| | Floating capacitance | C _f | V=0, f=1MHz | — | 0.6 | 1.0 | pF |
| | Cut-off frequency | f _c | V _{CC} =5V, I _C =2mA, R _L =100ohm | — | 7 | — | kHz |
| | Response time (Rise) | t _r | V _{CE} =2V, I _C =20mA, R _L =100ohm | — | 60 | 300 | us |
| | Response time (Fall) | t _f | | — | 50 | 250 | us |

Classification table of current transfer ratio is shown below.

| Model NO. | CTR (%) |
|-----------|--------------|
| *KP5010 A | 600 TO 2000 |
| KP5010 B | 1500 TO 4000 |
| KP5010 C | 3000 TO 6000 |
| *KP5010 D | 5000 TO 9000 |
| KP5010 E | 600 TO 9000 |

*SPECIAL OPTION

Fig.1 Current Transfer Ratio vs. Forward Current

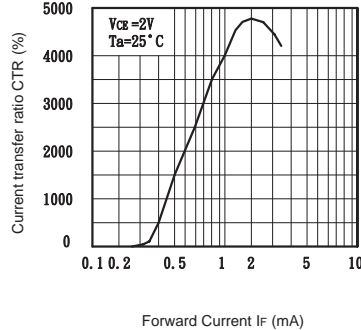


Fig.2 Collector Power Dissipation vs. Ambient Temperature

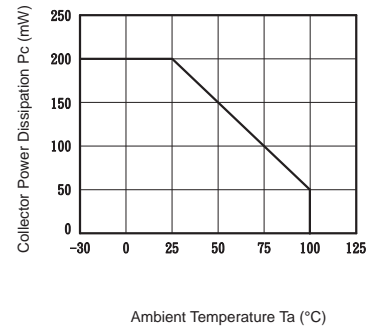


Fig.3 Collector Dark Current vs. Ambient Temperature

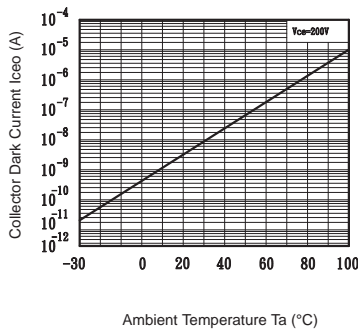


Fig.4 Forward Current vs. Ambient Temperature

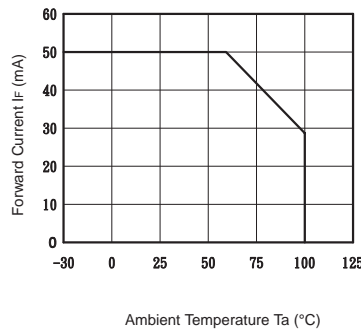


Fig.5 Forward Current vs. Forward Voltage

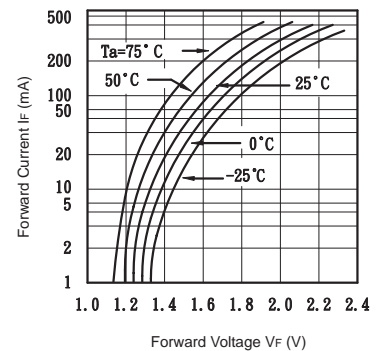


Fig.6 Collector Current vs. Collector-emitter Voltage

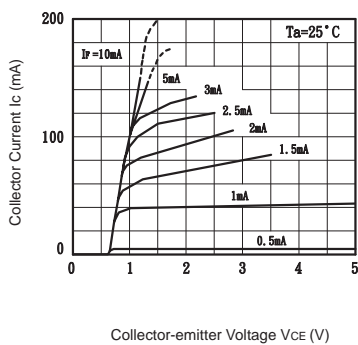


Fig.7 Relative Current Transfer Ratio vs. Ambient Temperature

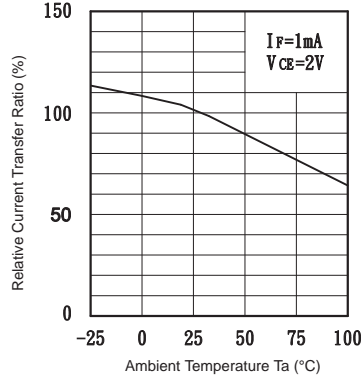


Fig.8 Collector-emitter Saturation Voltage vs. Forward Current

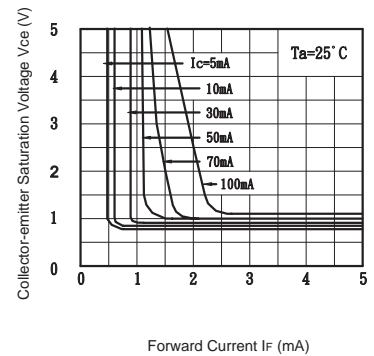


Fig.9 Response Time vs. Load Resistance

